



SEMICONDUCTOR

SRF1620 THRU SRF16200

SCHOTTKY BARRIER RECTIFIER

Reverse Voltage - 20 to 200 Volts

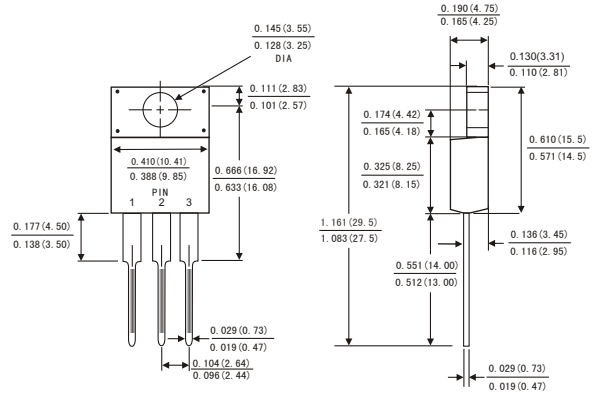
Forward Current - 16.0Amperes

FEATURES

- Plastic package has Underwriters Laboratory Flammability Classification 94V-0
- Metal silicon junction ,majority carrier conduction
- Guard ring for overvoltage protection
- Low power loss ,high efficiency
- High current capability ,Low forward voltage drop
- High surge capability
- For use in low voltage ,high frequency inverters, free wheeling ,and polarity protection applications
- Dual rectifier construction
- High temperature soldering guaranteed:260° C/10 seconds, 0.25"(6.35mm)from case
- Component in accordance to RoHS 2002/95/EC and WEEE 2002/96/EC



ITO-220AB



Dimensions in inches and (millimeters)

MECHANICAL DATA

- Case: JEDEC ITO-220AB molded plastic body
- Terminals: Lead solderable per MIL-STD-750,method 2026
- Polarity: As marked. No suffix indicates Common Cathode, suffix "A" indicates Common Anode
- Mounting Position: Any
- Weight: 0.08ounce, 2.24 gram

MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

(Ratings at 25°C ambient temperature unless otherwise specified ,Single phase ,half wave ,resistive or inductive load. For capacitive load, derate by 20%.)

	Symbols	SRF 1620	SRF 1630	SRF 1640	SRF 1650	SRF 1660	SRF 1680	SRF 16A0	SRF 16150	SRF 16200	Units	
Maximum repetitive peak reverse voltage	V _{RRM}	20	30	40	50	60	80	100	150	200	Volts	
Maximum RMS voltage	V _{RMS}	14	21	28	35	42	56	70	105	140	Volts	
Maximum DC blocking voltage	V _{DC}	20	30	40	50	60	80	100	150	200	Volts	
Maximum average forward rectified current See Fig. 1	I(AV)	16.0									Amps	
Peak forward surge current 8.3ms single half sine-wave superimposed on rated load (JEDEC method)	I _{FSM}	200.0									Amps	
Maximum instantaneous forward voltage at 16.0 A	V _F	0.55			0.70			0.85			Volts	
Maximum instantaneous reverse current at rated DC blocking voltage(Note 1)	I _R	0.5									mA	
		30			50							
Typical thermal resistance (Note 2)	R _{θJC}	3.0									°C/W	
Operating junction temperature range	T _J	-65 to+125				-65 to+150						°C
Storage temperature range	T _{STG}	-65 to+150									°C	

Notes: 1.Pulse test: 300 μs pulse width,1% duty cycle

2.Thermal resistance from junction to case

RATINGS AND CHARACTERISTIC CURVES SRF1620-SRF16200

FIG.1-FORWARD CURRENT DERATING CURVE

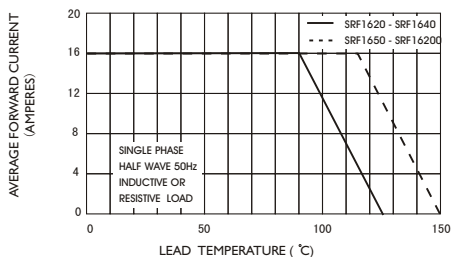


FIG.2-TYPICAL INSTANTANEOUS FORWARD CHARACTERISTICS

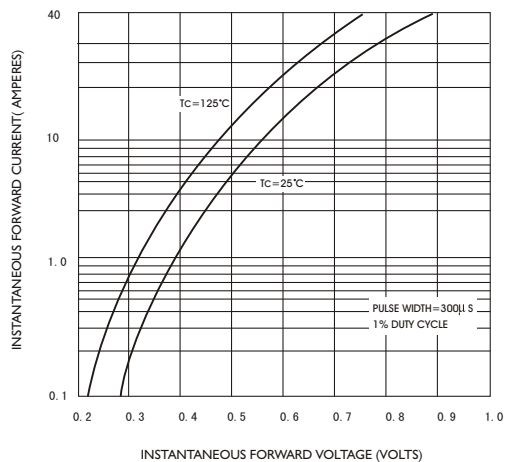


FIG.4-TYPICAL JUNCTION CAPACITANCE

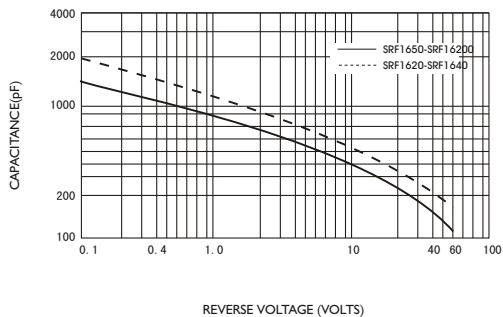


FIG.3-TYPICAL REVERSE CHARACTERISTICS

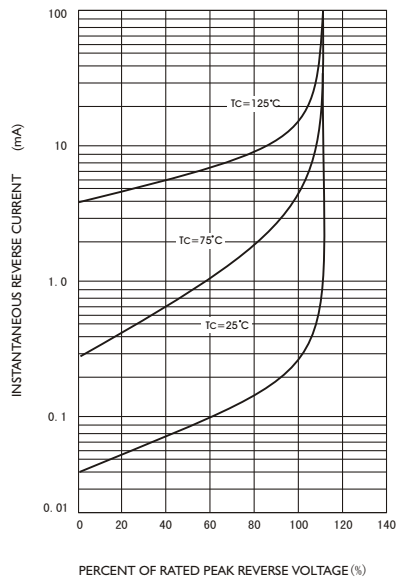


FIG.5-MAXIMUM NON-REPETITIVE PEAK FORWARD SURGE CURRENT

